

TBB1002

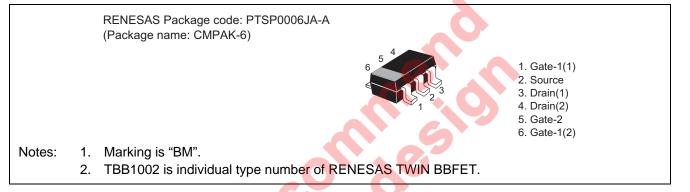
Twin Built in Biasing Circuit MOS FET IC VHF/UHF RF Amplifier

R07DS0313EJ1000 (Previous: REJ03G0841-0900) Rev.10.00 Mar 28, 2011

Features

- Small SMD package CMPAK-6 built in twin BBFET; To reduce using parts cost & PC board space.
- Suitable for World Standard Tuner RF amplifier.
- Very useful for total tuner cost reduction.
- Withstanding to ESD; Built in ESD absorbing diode. Withstand up to 200 V at C = 200 pF, Rs = 0 conditions.
- Provide mini mold packages; CMPAK-6

Outline



Absolute Maximum Ratings

	$(Ta = 25^{\circ}C)$		
Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DS}	6	V
Gate1 to source voltage	V _{G1S}	+6	V
		-0	
Gate2 to source voltage	V _{G2S}	+6	V
		-0	
Drain current	I _D	30	mA
Channel power dissipation	Pch ^{*3}	250	mW
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 3. Value on the glass epoxy board (49mm \times 38mm \times 1mm).



2500

Electrical Characteristics

The below specification are applicable for UHF unit (FET1)

						$(Ta = 25^{\circ}C)$
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	V _{(BR)DSS}	6		-	V	$I_D = 200 \ \mu A, \ V_{G1S} = V_{G2S} = 0$
Gate1 to source breakdown voltage	$V_{(BR)G1SS}$	+6			V	$I_{G1} = +10 \ \mu A, \ V_{G2S} = V_{DS} = 0$
Gate2 to source breakdown voltage	$V_{(BR)G2SS}$	+6			V	I_{G2} = +10 μ A, V_{G1S} = V_{DS} = 0
Gate1 to source cutoff current	I _{G1SS}	—		+100	nA	V_{G1S} = +5 V, V_{G2S} = V_{DS} = 0
Gate2 to source cutoff current	I _{G2SS}	—		+100	nA	$V_{G2S} = +5 V, V_{G1S} = V_{DS} = 0$
Gate1 to source cutoff voltage	V _{G1S(off)}	0.5	0.75	1.0	V	$V_{DS} = 5 V$, $V_{G2S} = 4 V$
						I _D = 100 μA
Gate2 to source cutoff voltage	V _{G2S(off)}	0.5	0.75	1.0	V	$V_{DS} = 5 V, V_{G1S} = 5 V$
						I _D = 100 μA
Drain current	I _{D(op)}	13	17	21	mA	$V_{DS} = 5 V, V_{G1} = 5 V$
						$V_{G2S} = 4 V, R_G = 100 k\Omega$
Forward transfer admittance	y _{fs}	21	26	31	mS	$V_{DS} = 5 V, V_{G1} = 5 V, V_{G2S} = 4 V$
						$R_G = 100 \text{ k}\Omega, \text{ f} = 1 \text{ kHz}$
Input capacitance	Ciss	1.4	1.8	2.2	pF	$V_{DS} = 5 V, V_{G1} = 5 V$
Output capacitance	Coss	1.0	1.4	1.8	pF	$V_{G2S} = 4 \text{ V}, \text{ R}_{G} = 100 \text{ k}\Omega$
Reverse transfer capacitance	Crss	—	0.02	0.04	pF	f = 1 MHz
Power gain	PG	16	21		dB	$V_{DS} = V_{G1} = 5 V, V_{G2S} = 4 V$
Noise figure	NF	_	1.7	2.5	dB	R _G = 100 kΩ, f = 900 MHz
						Zi =S11*, Zo=S22*(:PG)
						Zi =S11opt (:NF)

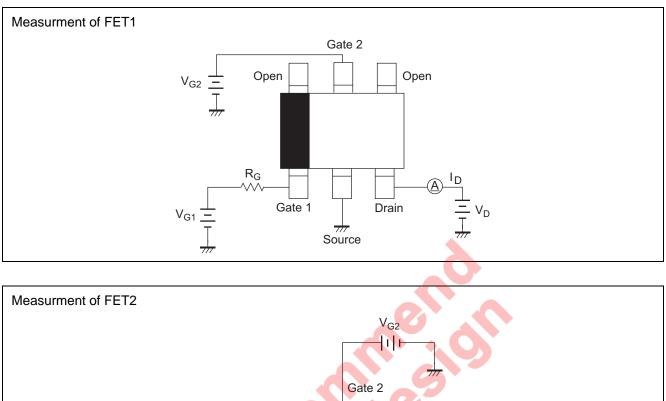
The below specification are applicable for VHF unit (FET2)

						$(Ta = 25^{\circ}C)$
ltem	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	V _{(BR)DSS}	6		_	V	$I_D = 200 \ \mu A, \ V_{G1S} = V_{G2S} = 0$
Gate1 to source breakdown voltage	V _{(BR)G1SS}	+6	—	—	V	$I_{G1} = +10 \ \mu A, \ V_{G2S} = V_{DS} = 0$
Gate2 to source breakdown voltage	V _{(BR)G2SS}	+6	_	_	V	$I_{G2} = +10 \ \mu A, \ V_{G1S} = V_{DS} = 0$
Gate1 to source cutoff current	I _{G1SS}	-		+100	nA	$V_{G1S} = +5 V, V_{G2S} = V_{DS} = 0$
Gate2 to source cutoff current	I _{G2SS}	—	—	+100	nA	$V_{G2S} = +5 V, V_{G1S} = V_{DS} = 0$
Gate1 to source cutoff voltage	V _{G1S(off)}	0.5	0.75	1.0	V	$V_{DS} = 5 V, V_{G2S} = 4 V$
						I _D = 100 μA
Gate2 to source cutoff voltage	V _{G2S(off)}	0.5	0.75	1.0	V	$V_{DS} = 5 V, V_{G1S} = 5 V$
						I _D = 100 μA
Drain current	I _{D(op)}	14	18	22	mA	$V_{DS} = 5V, V_{G1} = 5 V, V_{G2S} = 4 V$
						$R_{G} = 82 \text{ k}\Omega$
Forward transfer admittance	y _{fs}	20	25	30	mS	$V_{DS} = 5 V, V_{G1} = 5 V$
						V_{G2S} = 4 V, R_G = 82 k Ω
						f = 1 kHz
Input capacitance	Ciss	2.2	2.6	3.0	pF	$V_{DS} = 5 V, V_{G1} = 5 V$
Output capacitance	Coss	1.2	1.6	2.0	pF	V_{G2S} =4 V, R_{G} = 82 k Ω
Reverse transfer capacitance	Crss	—	0.03	0.05	pF	f = 1 MHz
Power gain	PG	22	27		dB	$V_{DS} = V_{G1} = 5 V, V_{G2S} = 4 V$
Noise figure	NF	_	1.2	1.7	dB	$R_{G} = 82 \text{ k}\Omega, \text{ f} = 200 \text{ MHz}$



Test Circuits

• DC Biasing Circuit for Operating Characteristic Items (I_{D(op)}, |yfs|, Ciss, Coss, Crss, NF, PG)



Gate 1

Open

 R_{G}

Drain

Open

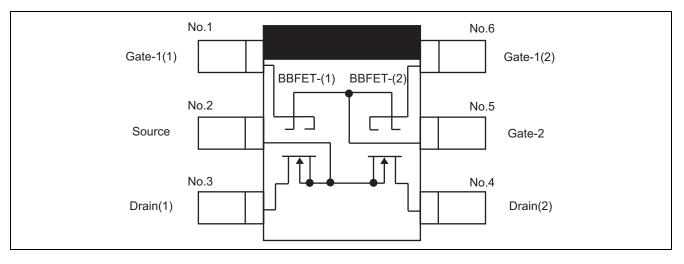
Source

 $(A) \stackrel{I_D}{-}$

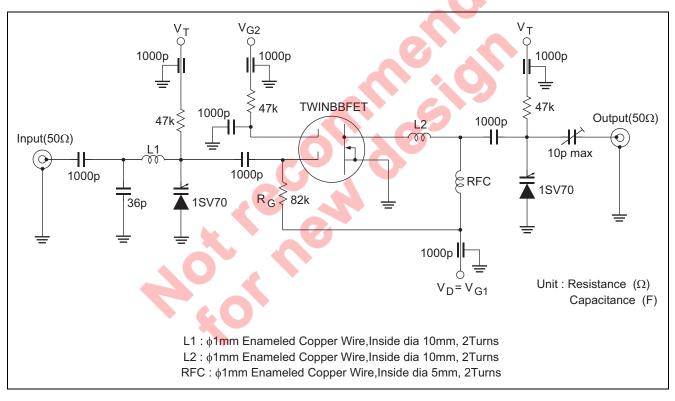
 V_D



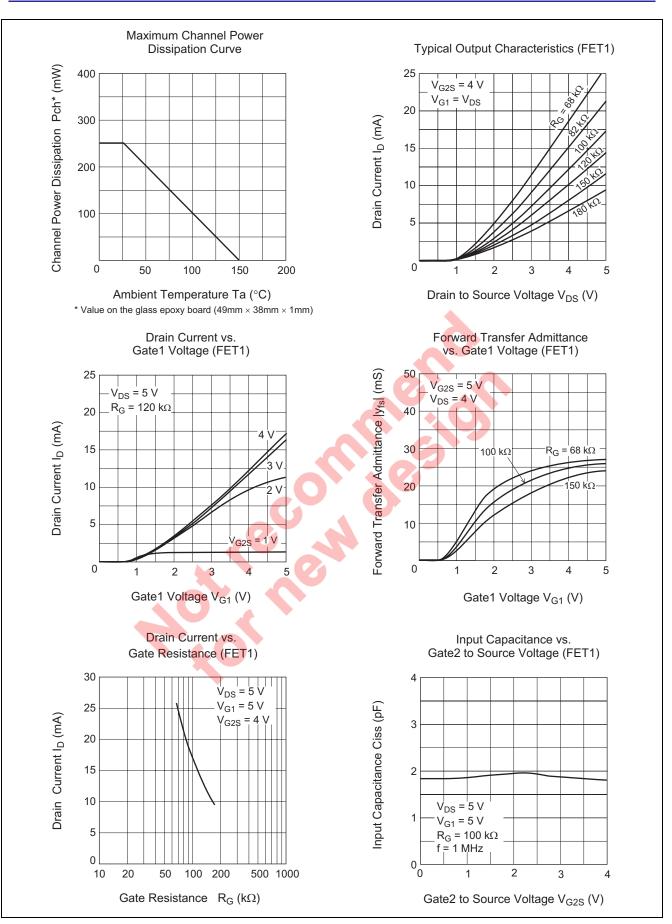
• Equivalent Circuit



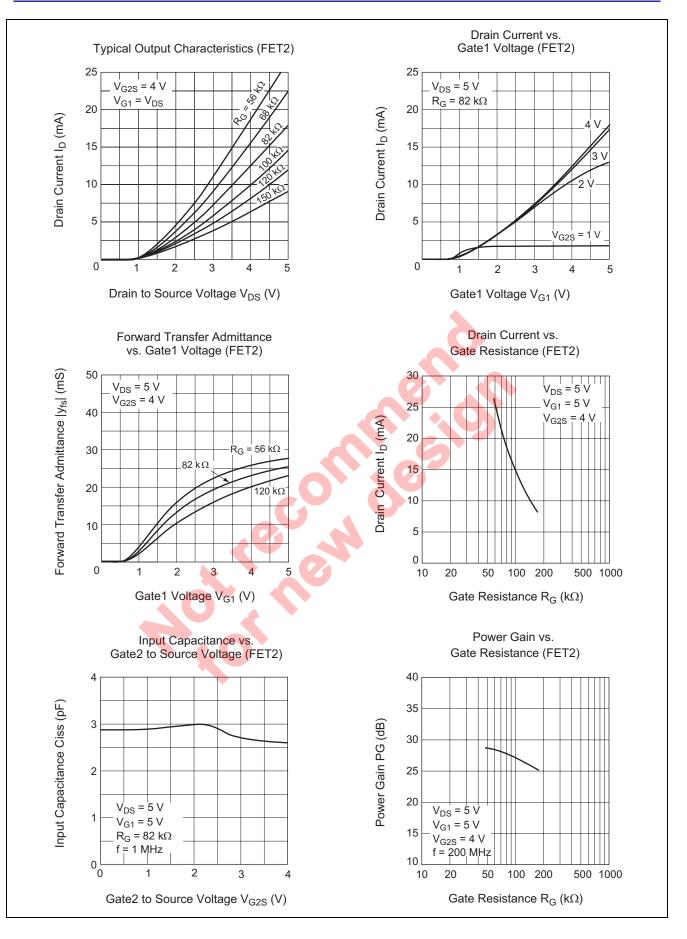
• 200 MHz Power Gain, Noise Figure Test Circuit

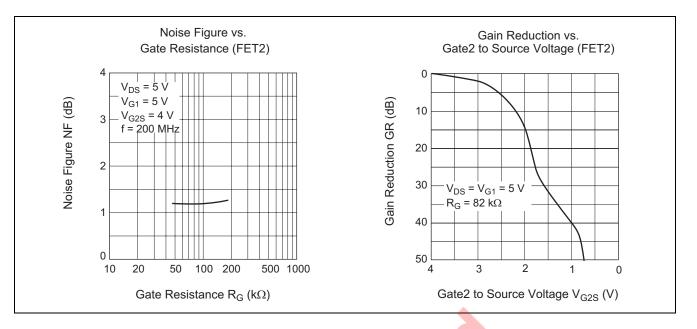






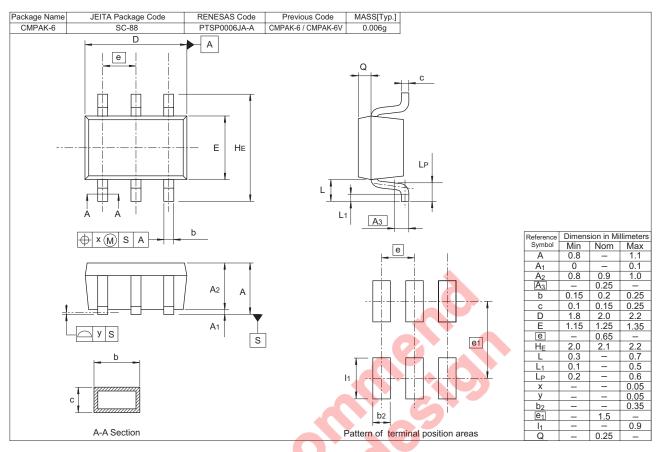








Package Dimensions



Ordering Information

Orderable Part Number	Quantity		Shipping Container
TBB1002BMTL-E	3000	φ 178	mm Reel, 8 mm Emboss Taping
TBB1002BMTL-H			

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.



Notice

- All information included in this document is current as of the date this document is issued. Such information, however, is subject to change without any prior notice. Before purchasing or using any Renesas Electronics products listed herein, please confirm the latest product information with a Renesas Electronics sales office. Also, please pay regular and careful attention to additional and different information to be disclosed by Renesas Electronics such as that disclosed through our website.
- Renesas Electronics does not assume any liability for infringement of patents, copyrights, or other intellectual property rights of third parties by or arising from the use of Renesas Electronics products or technical information described in this document. No license, express, implied or otherwise, is granted hereby under any patents, copyrights or other intellectual property rights of Renesas Electronics or others.
- 3. You should not alter, modify, copy, or otherwise misappropriate any Renesas Electronics product, whether in whole or in part.
- 4. Descriptions of circuits, software and other related information in this document are provided only to illustrate the operation of semiconductor products and application examples. You are fully responsible for the incorporation of these circuits, software, and information in the design of your equipment. Renesas Electronics assumes no responsibility for any losses incurred by you or third parties arising from the use of these circuits, software, or information.
- 5. When exporting the products or technology described in this document, you should comply with the applicable export control laws and regulations and follow the procedures required by such laws and regulations. You should not use Renease Electronics products or the technology described in this document for any purpose relating to military applications or use by the military, including but not limited to the development of weapons of mass destruction. Renease Electronics products and technology may not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any applicable domestic or foreign laws or regulations.
- 6. Renesas Electronics has used reasonable care in preparing the information included in this document, but Renesas Electronics does not warrant that such information is error free. Renesas Electronics assumes no liability whatsoever for any damages incurred by you resulting from errors in or omissions from the information included herein.
- 7. Renesas Electronics products are classified according to the following three quality grades: "Standard", "High Quality", and "Specific". The recommended applications for each Renesas Electronics product depends on the product's quality grade, as indicated below. You must check the quality grade of each Renesas Electronics product before using it in a particular application. You may not use any Renesas Electronics product for any application categorized as "Specific" without the prior written consent of Renesas Electronics. Further, you may not use any Renesas Electronics product for any application for which it is not intended without the prior written consent of Renesas Electronics and use any Renesas Electronics product for any application arising from the use of any Renesas Electronics product for an application categorized as "Specific" or for which the product is not intended where you have failed to obtain the prior written consent of Renesas Electronics. The quality grade of each Renesas Electronics product for any application categorized as "Specific" or for which the product is not intended where you have failed to obtain the prior written consent of Renesas Electronics. The quality grade of each Renesas Electronics product is expressly specified in a Renesas Electronics data sheets or data books, etc.
 - "Standard": Computers; office equipment; communications equipment; test and measurement equipment; audio and visual equipment; home electronic appliances; machine tools personal electronic equipment; and industrial robots.
 - "High Quality": Transportation equipment (automobiles, trains, ships, etc.); traffic control systems; anti-disaster systems; anti-crime systems; safety equipment; and medical equipment not specifically designed for life support.
 - "Specific": Aircraft; aerospace equipment; submersible repeaters; nuclear reactor control systems; medical equipment or systems for life support (e.g. artificial life support devices or systems), surgical implantations, or healthcare intervention (e.g. excision, etc.), and any other applications or purposes that pose a direct threat to human life.
- 8. You should use the Renesas Electronics products described in this document within the range specified by Renesas Electronics, especially with respect to the maximum rating, operating supply voltage range, movement power voltage range, heat radiation characteristics, installation and other product characteristics. Renesas Electronics shall have no liability for malfunctions or damages arising out of the use of Renesas Electronics products beyond such specified ranges.
- 9. Although Renesas Electronics endeavors to improve the quality and reliability of its products, semiconductor products have specific characteristics such as the occurrence of failure at a certain rate and malfunctions under certain use conditions. Further, Renesas Electronics products are not subject to radiation resistance design. Please be sure to implement safety measures to guard them against the possibility of physical injury, and injury or damage caused by fire in the event of the failure of a Renesas Electronics product, such as safety design for hardware and software including but not limited to redundancy, fire control and malfunction provention, appropriate treatment for aging degradation or any other appropriate measures. Because the evaluation of microcomputer software alone is very difficult, please evaluate the safety of the final products or system manufactured by you.
- 10. Please contact a Renesas Electronics sales office for details as to environmental matters such as the environmental compatibility of each Renesas Electronics product. Please use Renesas Electronics products in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive. Renesas Electronics assumes no liability for damages or losses occurring as a result of your noncompliance with applicable laws and regulations.
- 11. This document may not be reproduced or duplicated, in any form, in whole or in part, without prior written consent of Renesas Electronics.
- 12. Please contact a Renesas Electronics sales office if you have any questions regarding the information contained in this document or Renesas Electronics products, or if you have any other inquiries.
- (Note 1) "Renesas Electronics" as used in this document means Renesas Electronics Corporation and also includes its majority-owned subsidiaries.
- (Note 2) "Renesas Electronics product(s)" means any product developed or manufactured by or for Renesas Electronics.

Refer to "http://www.renesas.com/" for the latest and detailed information.



SALES OFFICES

Renesas Electronics Corporation

http://www.renesas.com

Renease Electronics America Inc. 2880 Scott Boulevard Santa Clarg CA 95050-2554, U.S.A. Tel: +1-408-588-8000, Fax: +1-409-588-6130 Renease Electronics Canada Limited 1101 Nicholson Road, Newmarket, Ontario L3Y 9C3, Canada Tel: +1-905-898-5441, Fax: +1-905-898-3220 Renease Electronics Europe Limited Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K Tel: +44-1025-685-100, Fax: +44-1022-565-900 Renease Electronics Europe GmbH Arcadiastrasse 10, 40472 Düsseldorf, Germany Tel: +49-21-65030, Fax: +44-1022-565-900 Renease Electronics (China) Co., Ltd. 7th Floor, Quantum Plaza, No.27 ZhiChuntu Haidian District, Beijing 100083, P.R.China Tel: +86-10-825-1155, Fax: +86-10-825-7679 Renease Electronics (Shanghai) Co., Ltd. 7th Floor, AziA Conter, No.1233 Luijazui Ring Rd, Pudong District, Shanghai 200120, China Tel: +86-10-5877-1181, Fax: +86-21-6887-7888 Renease Electronics (Shanghai) Co., Ltd. 7th Floor, S.ZIA/Conter, No.1233 Luijazui Ring Rd, Pudong District, Shanghai 200120, China Tel: +86-21-5877-1181, Fax: +86-21-6887-7888 Renease Electronics Hong Kong Limited 1011 1010-1613, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong 1011 1037, No. 363, Fu Shing North Road, Taipei, Taiwan Tel: +882-2866-9318, Fax: +862-21-5877 Renease Electronics Singapore Pte. Ltd. 11 Pati 75-9600, Fax: +862-2817-5970 Renease Electronics Malaysia Sdn.Bhd. 11 Pati 75-9600, Fax: +862-2817-5970 Renease Electronics Malaysia Sdn.Bhd. 11 Pati 75-9600, Fax: +862-2817-5970 Renease Electronics Malaysia Sdn.Bhd. 11 Pati -482-2950, Pax: +862-2817-5970 Renease Electronics Malaysia Sdn.Bhd. 11 Pati -482-2950, Pax: +862-28-801 Renease Electronics Malaysia Sdn.Bhd. 11 Pati -597-970, Pax: +862-78-801 Renease Electronics Malaysia Sdn.Bhd. 11 Pati -597-970, Pax: +862-78-801 Renease Electronics Malaysia Sdn.Bhd. 11 Pati -397-975-9390, Fax: +60-3-7955-9301 Renease Electronics Malaysia Sdn.Bhd. 11 Pati -397-975-9390, Fax: +60-3-7955-9510 Renease Electroni